

NASA Evaluation of Automotive Grade Microcircuits

NASA Electronic Parts & Packaging Program (NEPP)
Electronics Technology Workshop (ETW)

GSFC, Greenbelt, Maryland June 17 – 19, 2014

S. Agarwal

NASA - Jet Propulsion Laboratory, California Institute of Technology
Pasadena, California, USA
Shri.g.agarwal@jpl.nasa.gov

The outer zones of the solar system, which Voyager 1 has traversed to enter interstellar space. Courtesy NASA/IBEX/Adier Planetarium

www.nasa.gov

Evaluation of Automotive Grade Microcircuits

- This talk will give status of the work being performed at
 - Navy Crane, Indianapolis, Indiana
 - DPA Components International in Simi Valley, California
 - All parts are in plastic packages

Automotive Grade Parts Evaluation at Navy Crane

Navy Crane

- Joint NASA/Navy Crane Effort
- Coordinated by Josh Gray of Navy Crane
- Limited funds
- Three commodities being evaluated.
 - Passives
 - Led by Jay Brusse (NASA/GSFC)
 - Discrete Semiconductors
 - Led by Benny Damron (NASA/MSFC)
 - Microcircuits
 - Led by Shri Agarwal (NASA/JPL)
- Periodic telecons are held
 - Participants: J. Gray, J. Brusse, B. Damron, S. Agarwal, M. Sampson, C.
 Barnes

Automotive Grade Microcircuits Evaluation at DPACI

- DPA Components International (DPACI)
 - NASA/JPL contract at DPACI to
 - o Evaluate a digital IC from a high volume auto parts supplier
 - Status
 - Parts on order
 - Developing electrical test program

Microcircuits Planned Evaluation

- The microcircuits evaluation is divided into four phases
 - Phase I.
 - Assess quality (of parts as received)
 - 100% Electrical testing
 - Sample DPA
 - Phase II.
 - Assess infant mortality
 - 100% screening
 - Phase III.
 - Assess reliability
 - Sample life test
 - Phase IV.
 - o Additional Quality Conformance Inspection (QCI) tests
 - ❖ TBD

Automotive Grade Microcircuits Evaluation Parts Selection

- Vendor / Part Type Selection
 - Texas Instruments (TI).
 - Linear function
 - Digital function
 - Analog Devices, Inc. (ADI)
 - o Linear
 - ON Semiconductor (ON)
 - Digital function
 - MSI complexity
 - o Minimum time for test program development

From Discussion on Automotive Parts

Existing automotive parts market

- Plastic packages
- No screening is done
- Much testing is done at the wafer level
- Limited qualification
- The customer must enforce any desired requirements
- Manufacturers self certify—no DLA-type regulators
- The system works because of high-volume production—That is the customer's power to enforce upgrades

Microcircuit Evaluation is in progress (2014)

- In progress
- Screening and qualification are planned
 - Qualification will be limited to life test

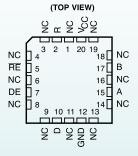
- Meets or Exceeds the Requirements of ANSI Standard TIA/EIA-485-A and ISO 8482:1987(E)
- High-Speed Low-Power LinBiCMOS™ Circuitry
- Designed for High-Speed Operation in Both Serial and Parallel Applications
- Low Skew
- **Designed for Multipoint Transmission on** Long Bus Lines in Noisy Environments
- Very Low Disabled Supply Current . . . 200 μ**A Maximum**
- Wide Positive and Negative Input/Output **Bus Voltage Ranges**
- Thermal-Shutdown Protection
- **Driver Positive-and Negative-Current** Limiting
- **Open-Circuit Failsafe Receiver Design**
- Receiver Input Sensitivity . . . ±200 mV Max
- Receiver Input Hysteresis . . . 50 mV Typ
- Operates From a Single 5-V Supply
- Glitch-Free Power-Up and Power-Down Protection
- Available in Q-Temp Automotive **HighRel Automotive Applications Configuration Control / Print Support Qualification to Automotive Standards**

description

SN65LBC176. The SN55LBC176. SN65LBC176Q, and SN75LBC176 differential bus transceivers are monolithic, integrated circuits designed for bidirectional data communication on multipoint bus-transmission lines. They are designed for balanced transmission lines and meet ANSI Standard TIA/EIA-485-A (RS-485) and ISO 8482:1987(E).



FK PACKAGE



NC-No internal connection

Function Tables

DRIVER

INPUT	ENABLE	OUTPUTS	
D	DE	Α	В
Н	Н	Н	L
L	Н	L	Н
Х	L	Z	Z

RECEIVER

DIFFERENTIAL INPUTS V _{ID} = V _{IA} – V _{IB}	ENABLE RE	OUTPUT R
V _{ID} ≥ 0.2 V	L	Н
$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$	L	?
V _{ID} ≤ -0.2 V	L	L
X	Н	Z
Open	L	Н

H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)



NEPAG

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinBiCMOS and LinASIC are trademarks of Texas Instruments Incorporated.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Copyright @ 2000-2006, Texas Instruments Incorporated on products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.





(Note: Microdot may be in either location)



Zero-Drift, Single-Supply, Rail-to-Rail Input/Output Operational Amplifier

w SOIC and

14-lead TSSOP plastic packages. See the Ordering Guide for automotive grades.





http://nepp.nasa.gov



ACKNOWLEDGMENTS

The research described in this publication was carried out, in part, at the Jet Propulsion Laboratory, California Institute of Technology, under a contract with the National Aeronautics and Space Administration. Help is gratefully acknowledged from Dr. Charles Barnes, Roger Carlson, Joon Park, and Michael Sampson. Copyright 2014 California Institute of Technology. Government sponsorship acknowledged.